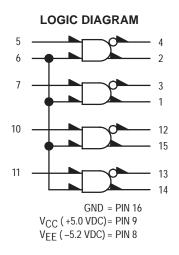
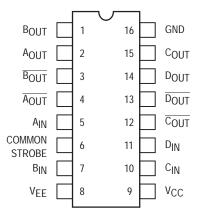
Quad TTL-to-MECL Translator With TTL Strobe Input

The MC10H124 is a quad translator for interfacing data and control signals between a saturated logic section and the MECL section of digital systems. The 10H part is a functional/pinout duplication of the standard MECL 10K family part, with 100% improvement in propagation delay, and no increase in power–supply current.

- Propagation Delay, 1.5 ns Typical
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K-Compatible



DIP PIN ASSIGNMENT



Pin assignment is for Dual–in–Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).

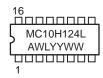


http://onsemi.com

MARKING DIAGRAMS



CDIP-16 L SUFFIX CASE 620





PDIP-16 P SUFFIX CASE 648





PLCC-20 FN SUFFIX CASE 775



A = Assembly Location

WL = Wafer Lot YY = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC10H124L	CDIP-16	25 Units/Rail
MC10H124P	PDIP-16	25 Units/Rail
MC10H124FN	PLCC-20	46 Units/Rail

MC10H124

MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
VEE	Power Supply (V _{CC} = 5.0 V)	-8.0 to 0	Vdc
Vcc	Power Supply (V _{EE} = -5.2 V)	0 to +7.0	Vdc
V _I	Input Voltage (V _{CC} = 5.0 V) TTL	0 to V _{CC}	Vdc
l _{out}	Output Current — Continuous — Surge	50 100	mA
TA	Operating Temperature Range	0 to +75	°C
T _{stg}	Storage Temperature Range — Plastic — Ceramic	−55 to +150 −55 to +165	°C

ELECTRICAL CHARACTERISTICS ($V_{EE} = -5.2 \text{ V} \pm 5\%$, $V_{CC} = 5.0 \text{ V} \pm 5.0\%$)

		0 °		25°		75°		
Symbol	Characteristic	Min	Max	Min	Max	Min	Max	Unit
IE Negative Power Supply Drain Current		_	72		66		72	mA
ICCH	Positive Power Supply	_	16		16		18	mA
ICCL	Drain Current	_	25	_	25	_	25	mA
I _R Reverse Current Pin 6 Pin 7		_	200 50	_ _	200 50	_ _	200 50	μΑ
I _F Forward Current Pin 6 Pin 7		_	-12.8 -3.2	_ _	-12.8 -3.2	_ _	-12.8 -3.2	mA
V(BR)in Input Breakdown Voltage		5.5	_	5.5	_	5.5	_	Vdc
VI	Input Clamp Voltage		-1.5	_	-1.5	_	-1.5	Vdc
Voн	High Output Voltage	-1.02	-0.84	-0.98	-0.81	-0.92	-0.735	Vdc
V _{OL}	Low Output Voltage	-1.95	-1.63	-1.95	-1.63	-1.95	-1.60	Vdc
VIH	High Input Voltage	2.0	_	2.0	_	2.0	_	Vdc
V _{IL}	Low Input Voltage	_	0.8	_	0.8	_	0.8	Vdc

^{1.} Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts.

ELECTRICAL CHARACTERISTICS ($V_{EE} = -5.2 \text{ V} \pm 5\%$, $V_{CC} = 5.0 \text{ V} \pm 5.0\%$)

		0 °		25°		75°		
Symbol	Characteristic	Min	Max	Min	Max	Min	Max	Unit
AC PARAM	AC PARAMETERS							
t _{pd}	Propagation Delay	0.55	2.25	0.55	2.4	0.85	2.95	ns
t _r	Rise Time	0.5	1.5	0.5	1.6	0.5	1.7	ns
t _f	Fall Time	0.5	1.5	0.5	1.6	0.5	1.7	ns

APPLICATIONS INFORMATION

The MC10H124 has TTL–compatible inputs and MECL complementary open–emitter outputs that allow use as an inverting/non–inverting translator or as a differential line driver. When the common strobe input is at the low–logic level, it forces all true outputs to a MECL low–logic state and all inverting outputs to a MECL high–logic state.

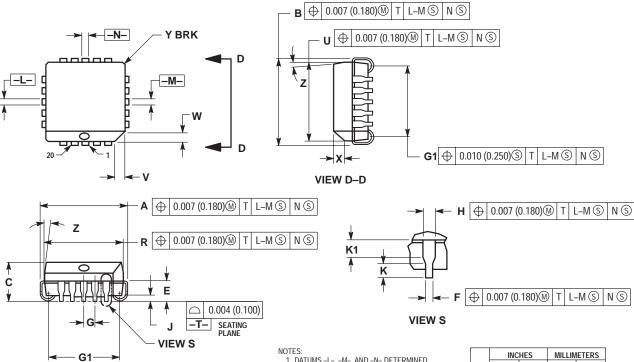
An advantage of this device is that TTL—level information can be transmitted differentially, via balanced twisted pair lines, to MECL equipment, where the signal can be received by the MC10H115 or MC10H116 differential line receivers. The power supply requirements are ground, +5.0 volts, and -5.2 volts.

MC10H124

PACKAGE DIMENSIONS

PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE C



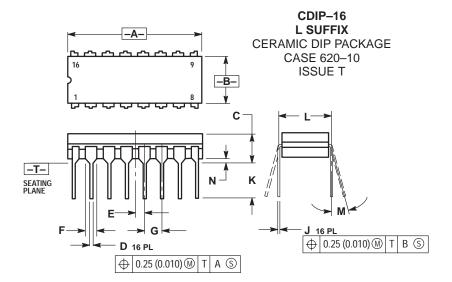
⊕ 0.010 (0.250)⑤ T L-M ⑤ N ⑤

- DATUMS -L-, -M-, AND -N- DETERMINED
 WHERE TOP OF LEAD SHOULDER EXITS PLASTIC WILLY LOVE LEAD STOUDER EXTENSIVE SOLUTION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE MOLD
- FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
 4. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 5. CONTROLLING DIMENSION: INCH.
- 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIN	IETERS			
DIM	MIN	MAX	MIN	MAX			
Α	0.385	0.395	9.78	10.03			
В	0.385	0.395	9.78	10.03			
С	0.165	0.180	4.20	4.57			
Е	0.090	0.110	2.29	2.79			
F	0.013	0.019	0.33	0.48			
G	0.050	BSC	1.27	BSC			
Н	0.026	0.032	0.66	0.81			
J	0.020		0.51				
K	0.025		0.64				
R	0.350	0.356	8.89	9.04			
U	0.350	0.356	8.89	9.04			
V	0.042	0.048	1.07	1.21			
W	0.042	0.048	1.07	1.21			
Χ	0.042	0.056	1.07	1.42			
Υ		0.020		0.50			
Z	2°	10 °	2 °	10 °			
G1	0.310	0.330	7.88	8.38			
K1	0.040		1.02				

MC10H124

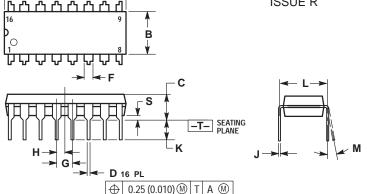


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEAD WHEN
- FORMED PARALLEL.
 DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC

	INC	HES	MILLIN	IETERS	
DIM	MIN	MIN MAX		MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Ε	0.050 BSC		1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	0.100 BSC		BSC	
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300 BSC		7.62	BSC	
M	0°	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100 BSC		2.54 BSC			
Н	0.050	BSC	1.27 BSC			
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
M	0°	10°	0 °	10 °		
S	0.020	0.040	0.51	1.01		

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